SCRs

Commercial Nanosecond Switching Planar

GA300 GB300 GA300A GB300A GA301 GB301 GA301A GB301A

FEATURES

- Rise Time: 10ns
- Delay Time: 10ns
- Recovery Time: 0.5μs
- Pulse Current: to 100A
- . Turn-on with 20ns, 10mA gate pulse

DESCRIPTION

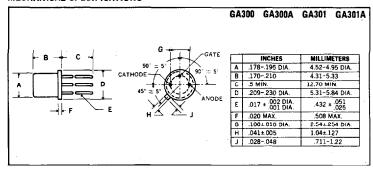
The Microsemi Nanosecond Thyristor Switch combines the turn-on speed of logic level transistors with the high current switching capability inherent in SCRs. With this device engineers can now design circuits capable of switching pulse currents of 1A in less than 10ns or up to 30A in less than 20ns.

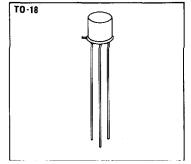
The GA300, GB300 Series is specifically designed for use as switching element in high speed laser diode pulse drivers. Other applications include electronic crowbars, harmonic wave-form generators, line drivers and general purpose replacements for avalanche transistors. For applications requiring higher voltage levels, Microsemi has developed several "series string" circuits which allow the series connection of an unlimited number of devices for voltages as high as 2000V with no significant decrease in speed. The circuits are described in Microsemi's Design Note #14.

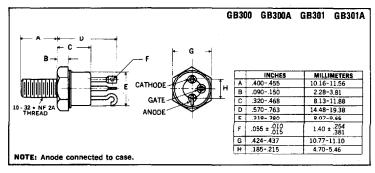
ABSOLUTE MAXIMUM RATINGS

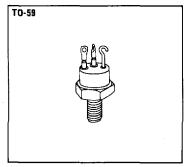
	GA300 GA300A	GA301 GA301A	GB300 GB300A	GB301 GB301A	
Repetitive Peak Off-State Voltage, VDRM	60V	100V	60V	100V	
Repetitive Peak On-State Current, ITRM	up to	100A	up to 100A		
Peak Gate Current, I _{GM}	250)mA	250mA		
Average Gate Current, IG(AV)	251	ma	501	nA	
Reverse Gate Current, I _{GR}	3n	nA	3mA		
Reverse Gate Voltage, V _{GR}	5	٧		V	
Storage Temperature Range		—65°C to	+150°C		
Operating Temperature Range		0°C to	+125°C		

MECHANICAL SPECIFICATIONS











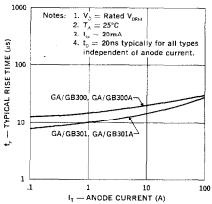
ŏ

ELECTRICAL SPECIFICATIONS (at 25°C unless noted)

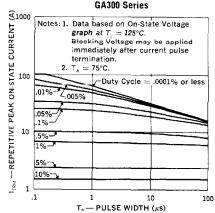
Test	Symbol	Min.	Typical	Max.	Units	Test Conditions
Nelay Time	t _a	_	20 10	30	ns	$I_G = 20$ mA, $I_T = 1$ A $I_G = 3$ UmA, $I_T = 1$ A
Rise Time (Note 1) GA300, 300A, GB300, 300A	t,	-	15 25	25 —	ns	$V_D = 60V, I_T = 1A$ $V_D = 60V, I_T = 30A$ (Note 1)
Rise Time (Note 1) GA301, 301A, GB301, 301A	t,	_	10 20	20	ns	$V_D = 100V, I_T = 1A$ (Note 1)
Circuit Commutated Turn-off Time GA300, 301, GB300, 301	t _q		0.8	2.0	μS	$I_T = IA$, $I_R = IA$, $R_{GK} = IK$
GA300A, 301A, GB300A, 301A	, °q		0.3	0.5	με	$I_T = 1A$, $I_R = 1A$, $R_{GK} = 1K$
Gate Trigger-on Pulse Width	t _{pg (on)}		0.02	0.05	μS	$I_G = 10$ mA, $I_T = 1$ A
Off-state Current	I _{DRM}	_	0.01 20	0.1 100	μ Α , Δ	V_{DRM} = Rating, R_{GK} = 1K, T = 25°C V_{UKM} = Rating, R_{CK} = 1K, T = 125°C
Reverse Current (Note 2)	I _{RRM}		1.0	10	mA	$V_{RRM} = 30V, R_{GK} = 1K$ (Note 2)
Gate Trigger Voltage	V _{GT}	0.4 0.10	0.6 0.2	0.75	V	$V_D = 5V, R_{GS} = 100\Omega, T = 25^{\circ}C$ $V_D = 5V, R_{GS} = 100\Omega, T = 125^{\circ}C$
Gate Trigger Current	I _{GT}	-	10	200	μΑ	$V_D = 5V$, $R_{GS} = 10K$
On-state Voltage	V _T	_	1.1	1.5	٧	$I_{\uparrow} = 2A$
Off-state Voltage — Critical Rate of Rise	dv/dt	15	30		V/µs	$V_D = 30V$, $R_{GK} = 1K$
Reverse Gate Current	I _{GR}	=	0.01	0.1	mA	$V_{GR} = 5V$
Holding Current	I _H	0.3 0.05	2.0 0.4	5.0 —	mA mA	$V_D = 5V$, $R_{GK} = 1K$, $T = 25^{\circ}C$ $V_D = 5V$, $R_{GK} = 1K$, $T = 125^{\circ}C$

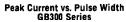
Notes: 1. I_e = 10mA₁ Pulse Test, Duty Cycle < 1%.
2. Pulse test intended to guarantee reverse anode voltage capability for pulse commutation. Device should not be operated in the reverse blocking mode on a continuous basis.

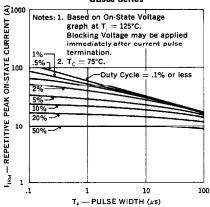
Switching Speed vs. Current GA/GB300 Series



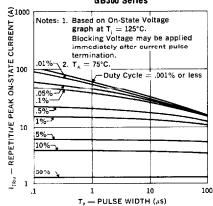
Peak Current vs. Pulse Width GA300 Series







Peak Current vs. Pulse Width GB300 Series



100 $T_{\rm i}=125^{\circ}{\rm C}$ 1, -- ON-STATE CURRENT (A) 10

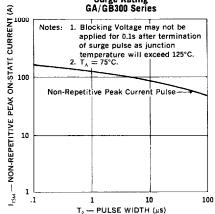
10

- ON-STATE VOLTAGE (V)

100

On-State Voltage vs. Current GA/GB300 Series

Surge Rating GA/GB300 Series



.1

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for SCRs category:

Click to view products by Microchip manufacturer:

Other Similar products are found below:

NTE5428 T1500N16TOF VT TT162N16KOF-A TT162N16KOF-K TT330N16AOF VS-22RIA20 VS-2N685 057219R T1190N16TOF VT T1220N22TOF VT T201N70TOH T700N22TOF T830N18TOF TT250N12KOF-K VS-16RIA120 VS-110RKI40 NTE5427 NTE5442 TT251N16KOF-K VS-22RIA100 VS-16RIA40 TD250N16KOF-A VS-ST110S16P0 T930N36TOF VT T2160N24TOF VT T1190N18TOF VT T1590N28TOF VT 2N1776A T590N14TOF NTE5375 NTE5460 NTE5481 NTE5512 NTE5514 NTE5518 NTE5519 NTE5529 NTE5553 NTE5557 NTE5557 NTE5567 NTE5570 NTE5572 NTE5574 NTE5576 NTE5578 NTE5579 NTE5589 NTE5598